

COMPLIANT

High Performance Schottky Rectifier, 200 A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	200 A			
V_{R}	135 V, 150 V			
Package	TO-244			
Circuit configuration	Two diodes common cathode			

FEATURES

- 175 °C T_{.1} operation
- · Center tap module
- · Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

The VS-209CNQ center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES			
I _{F(AV)}	Rectangular waveform	Rectangular waveform 200			
V_{RRM}	Range	135/150	V		
I _{FSM}	t _p = 5 μs sine	10 000	Α		
V _F	100 A _{pk} , T _J = 125 °C (per leg)	0.71	V		
T_J	Range	Range -55 to +175			

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-209CNQ135PbF	VS-209CNQ150PbF	UNITS
Maximum DC reverse voltage	V_{R}	135	150	V
Maximum working peak reverse voltage	V_{RWM}	133	130	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current per leg	J=	50 % duty cycle at T _C = 131 °C, rectangular waveform		100	
See fig. 5 per devie				200	
Maximum peak one cycle non-repetitive surge		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	10 000	A
current per leg See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse		1200	
Non-repetitive avalanche energy per leg E		$T_J = 25 ^{\circ}\text{C}, I_{AS} = 5.5 \text{A}, L = 1 \text{mH}$		15	mJ
Repetitive avalanche current per leg I _{AR}		Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А

Revision: 09-May-17 **1** Document Number: 94156



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V _{FM} ⁽¹⁾	100 A	T _{.1} = 25 °C	1.06	V
Maximum forward voltage drop per leg		200 A	1j=25 C	1.33	
See fig. 1		100 A	T 105 %C	0.74	
		200 A	T _J = 125 °C	0.88	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	3	mA
See fig. 2		T _J = 125 °C	V _R = nateu V _R	45	IIIA
Maximum junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		3000	pF
Typical series inductance per leg	L _S	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}	-55	-	175	°C	
Thermal resistance, junction to case	per leg	D	-	-	0.38	°C/W	
	per module	R_{thJC}	-	-	0.19		
Thermal resistance, case to heatsink		R _{thCS}	-	0.10	0 -		
Weight			-	68	_	g	
Weight				2.4		OZ.	
Mounting torque			35.4 (4)	-	53.1 (6)		
Mounting torque center hole			30 (3.4)	-	40 (4.6)	lbf ⋅ in (N ⋅ m)	
Terminal torque			30 (3.4)	-	44.2 (5)	(14 111)	
Vertical pull			-	-	80	llef in	
2" lever pull			-	-	35	—— lbf ⋅ in	

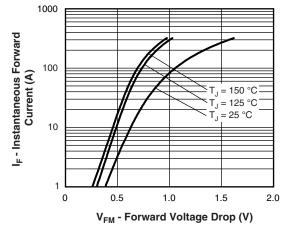


Fig. 1 - Maximum Forward Voltage Drop Characteristics

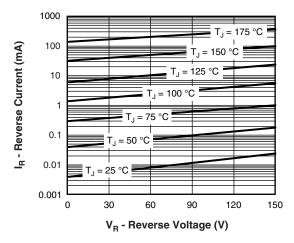


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

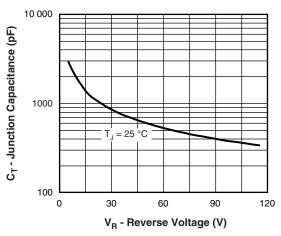


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

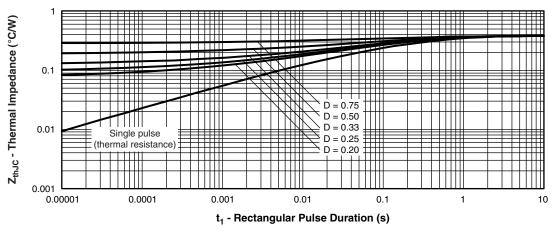


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

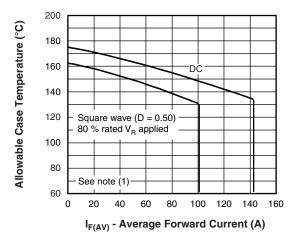


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

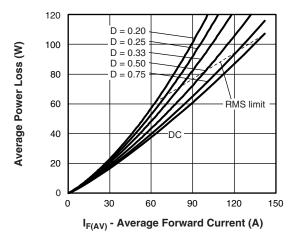
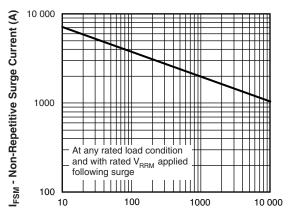


Fig. 6 - Forward Power Loss Characteristics



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

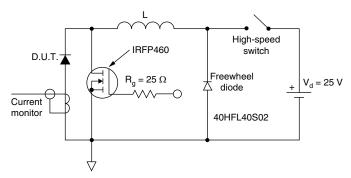


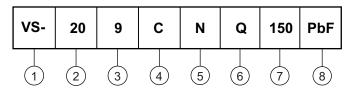
Fig. 8 - Unclamped Inductive Test Circuit

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Average current rating (x 10)

3 - Product silicon identification

4 - C = circuit configuration

5 - N = not isolated

6 - Q = Schottky rectifier diode

- Voltage ratings — 135 = 135 V 150 = 150 V

Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95021			



TO-244

DIMENSIONS in millimeters (inches)









Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.